

# Electro Deposition on PCB Process

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LG Electronics Inc.

## ELECTRO-DEPOSITION ON PCB PROCESS

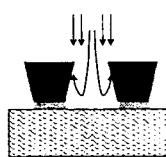
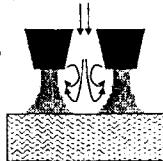
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### Trend of Fine Pattern technology ?

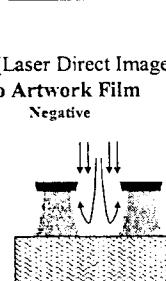
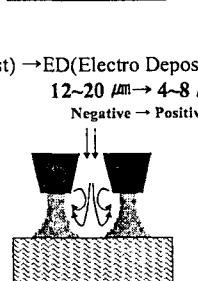
#### Advantages of Thin Photo Resist

1st issue, Thin Copper foil (Half Etching)  
 $36\mu m \rightarrow 18\mu m \rightarrow 12\mu m \rightarrow 9\mu m \rightarrow 5\mu m$



#### 2nd issues, Thin Photo Resist

Dry Film → LPR(Liquid Photo Resist) → ED(Electro Deposit) → LDI(Laser Direct Image)  
30~40 μm → 12~18 μm → 12~20 μm → 4~8 μm  
Negative Negative Negative → Positive w/o Artwork Film  
Negative



#### 3rd issues, High etching factor(Etching Chemical)

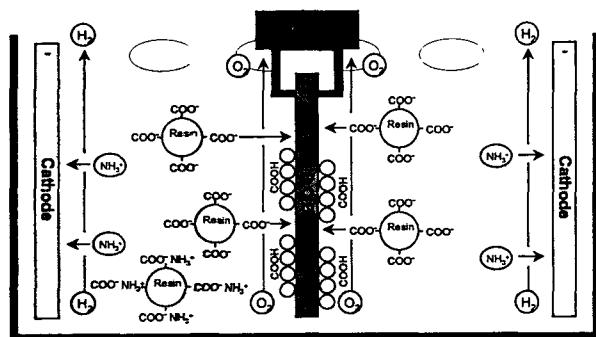
- Etching side-wall의 쇠각도 우수
- high Specific gravity(Fe<sub>2</sub>Cl<sub>3</sub>, NaClO<sub>3</sub> + CuCl<sub>2</sub>, etc)

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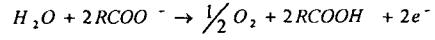
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## Electro-Deposition란?

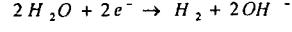
Resist particle 표면이 -로 하전된 Resist 입자가 Board에 + 전류가 흐를 때 전기적으로 축착되는 공법.



Reaction at Anode



Reaction at Cathode



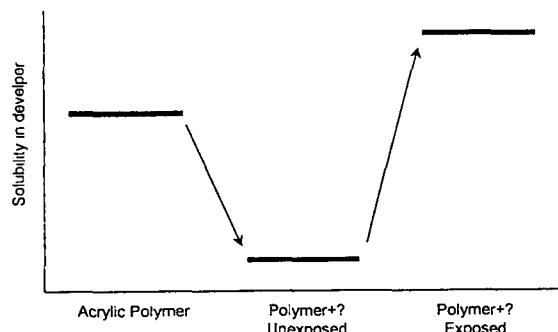
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## Exposure Mechanism

Photo Reaction Compound로 사용된 Photo inhibitor가 UV Light에 의해 현상액에서 chemical reaction에 의해 soluble한 상태로 전환됨.

- Positive resist solubility



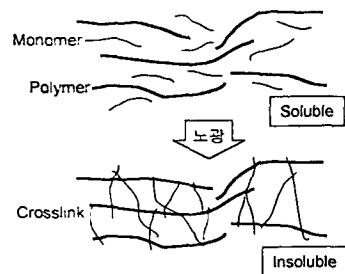
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### Negative vs. Positive Photoresist

#### Negative

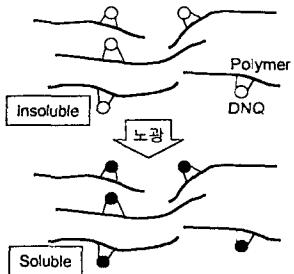
Dry Film, LPR, Negative ED resist  
50% monomer + 50% polymer



Application  
주요 구성성분

#### Positive

Positive ED resist  
80% polymer + 20% DNQ

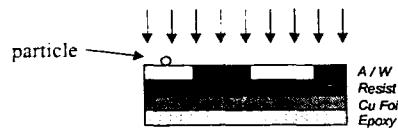


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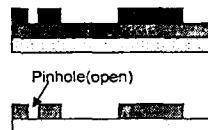
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### Negative vs. Positive Photoresist

#### Negative



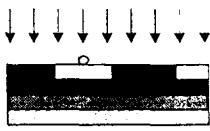
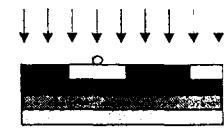
노광



현상

에칭/박리

#### Positive



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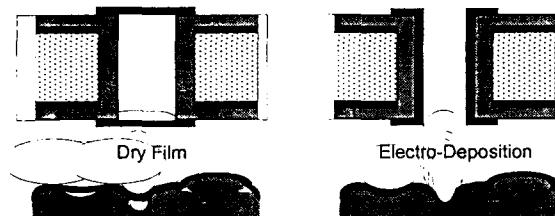
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## Dry Film vs. ED

- Production of high density design



- Three-dimensional capabilities



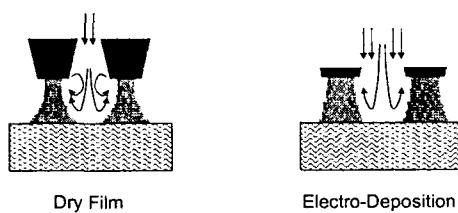
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## Dry Film vs. ED

### Advantages of ED Resist

- Etching 시 side-wall의 치각도 우수



- Etching speed 향상 (25%이상)

- Reduced waste

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## Negative vs. Positive Photoresist

### Negative

현상 시 유기용제가 노광부에도  
스며 들어가 Swelling현상 발생

분해능이 좋지 않음

노광 전 Soft and tacky  
(취급이 어려움)

Opens rather than shorts

High A/R ratio PTH에 불리  
(For negative ED)

가격이 저렴함

노광 시간이 짧음

### Positive

No Swelling

Fine Pattern 형성에 유리

Hard and no tacky

Shorts rather than opens  
(핀홀 방지)

High A/R ratio PTH에 유리

상대적으로 비쌈

노광 시간이 길

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## Dry Film vs. ED

Type of resist	Dry Film	ED Resist
Resist type	Negative	Positive
Film thickness ( $\mu m$ )	30 - 40	4 - 8
Exposure dose ( $mJ/cm^2$ )	50 - 80	300-800
Resolution ( $\mu m$ )	75	25
Hole formation	Difficult to form fine pitch T/H	Easy to form land-less, High Aspect ratio T-H
Adhesion to substrate	Poor	Good
Handling	Good	Fare
Resistance for particle	Poor	Good

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